

●特点：导通电阻低 开关速度快 输入阻抗高 符合RoHS规范

●FEATURES: ■LOW ON-RESISTANCE ■FAST SWITCHING ■HIGH INPUT RESISTANCE ■RoHS COMPLIANT

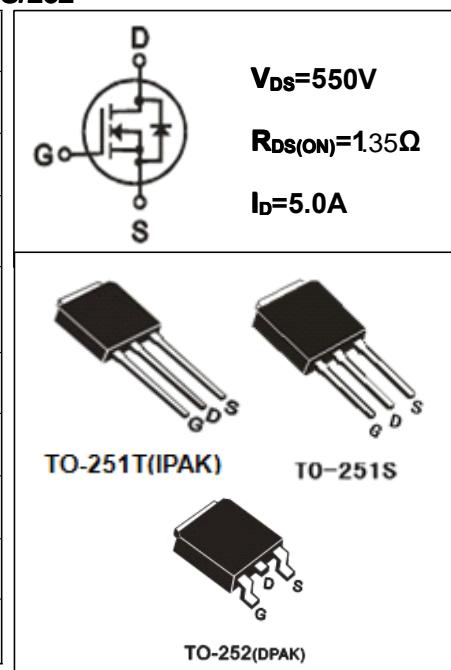
●应用：电子镇流器 电子变压器 开关电源

●APPLICATION: ■ELECTRONIC BALLAST■ELECTRONIC TRANSFORMER■SWITCH MODE POWER SUPPLY

### ●最大额定值 (Tc=25°C)

### ●Absolute Maximum Ratings (Tc=25°C) TO-251T/251S/252

参数 PARAMETER	符号 SYMBOL	额定值 VALUE	单位 UNIT
漏-源电压 Drain-source Voltage	V <sub>DS</sub>	550	V
栅-源电压 gate-source Voltage	V <sub>GS</sub>	± 30	V
漏极电流 Continuous Drain Current TC=25°C	I <sub>D</sub>	5.0*	A
漏极电流 Continuous Drain Current TC=100°C	I <sub>D</sub>	3.0*	A
最大脉冲电流 Drain Current - Pulsed ①	I <sub>DM</sub>	20*	A
耗散功率 Power Dissipation	P <sub>tot</sub>	50	W
最高结温 Junction Temperature	T <sub>j</sub>	150	°C
存储温度 Storage Temperature	T <sub>STG</sub>	-55-150	°C
单脉冲雪崩能量 Single Pulse Avalanche Energy ②	E <sub>AS</sub>	280	mJ



\*漏极电流由最高结温限制

\*Drain current limited by maximum junction temperature

### ●电特性 (Tc=25°C)

### ●Electronic Characteristics (Tc=25°C)

参数 PARAMETER	符号 SYMBOL	测试条件 TEST CONDITION	最小值 MIN	典型值 TYP	最大值 MAX	单位 UNIT
漏-源击穿电压 Drain-source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	500			V
击穿电压温度系数 Breakdown Voltage Temperature Coefficient	△BV <sub>DSS</sub> / △T <sub>j</sub>	I <sub>D</sub> =250μA, Referenced to 25°C		0.6		V/°C
栅极开启电压 Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>GS</sub> =V <sub>DS</sub> , I <sub>D</sub> =250μA	2.0		4.0	V
漏-源漏电流 Drain-source Leakage Current	I <sub>DSS</sub>	V <sub>DS</sub> =500V, V <sub>GS</sub> =0V, T <sub>j</sub> =25°C			25	μA
		V <sub>DS</sub> =400V, V <sub>GS</sub> =0V, T <sub>j</sub> =125°C			250	μA
跨导 Forward Transconductance	g <sub>fs</sub>	V <sub>DS</sub> =15V, I <sub>D</sub> =2.5A ③	2.4			S

参数 PARAMETER	符号 SYMBOL	测试条件 TEST CONDITION	最小值 MIN	典型值 TYP	最大值 MAX	单位 UNIT
栅极漏电流 Gate-body Leakage Current ( $V_{DS} = 0$ )	$I_{GSS}$	$V_{GS} = \pm 30V$			$\pm 100$	nA
漏-源导通电阻 Static Drain-source On Resistance	$R_{DS(ON)}$	$V_{GS} = 10V, I_D = 2.5A$ ③		1.35	1.5	$\Omega$
输入电容 Input Capacitance	$C_{iss}$	$V_{GS} = 0V, V_{DS} = 25V$ $F = 1.0MHz$		560		pF
输出电容 Output Capacitance	$C_{oss}$			45		
反向传输电容 Reverse transfer Capacitance	$C_{rss}$			17		
关断延迟 Turn -Off Delay Time	$T_{d(off)}$	$V_{DD} = 300V, I_D = 4.0A$ $R_G = 25\Omega$ ③		20		ns
栅极电荷 Total Gate Charge	$Q_g$	$I_D = 5.0A, V_{DS} = 480V$ $V_{GS} = 10V$ ③		26		nC
栅源电荷 Gate-to-Source Charge	$Q_{gs}$			4		nC
栅漏电荷 Gate-to-Drain Charge	$Q_{gd}$			15		nC
二极管正向电流 Continuous Diode Forward Current	$I_s$				5.0	A
二极管正向压降 Diode Forward Voltage	$V_{SD}$	$T_j = 25^\circ C, I_s = 5.0A$ $V_{GS} = 0V$ ③			1.6	V
反向恢复时间 Reverse Recovery Time	$t_{rr}$	$T_j = 25^\circ C, I_f = 5.0A$ $di/dt = 100A/\mu s$ ③		220		ns
反向恢复电荷 Reverse Recovery Charge	$Q_{rr}$			1.0		uC

## ●热特性

### ●Thermal Characteristics

参数 PARAMETER	符号 SYMBOL	最大值 MAX	单位 UNIT
热阻结-壳 Thermal Resistance Junction-case	$R_{thJC}$	2.50	$^\circ C/W$
热阻结-环境 Thermal Resistance Junction-ambient	$R_{thJA}$	110.0	$^\circ C/W$

### 注释(Notes):

① 脉冲宽度: 以最高结温为限制

Repetitive rating: Pulse width limited by maximum junction temperature

② 初始结温= $25^\circ C$ ,  $V_{DD} = 50V$ ,  $L = 24mH$ ,  $R_G = 25\Omega$ ,  $I_{AS} = 5.0A$

Starting  $T_j = 25^\circ C$ ,  $V_{DD} = 50V$ ,  $L = 24mH$ ,  $R_G = 25\Omega$ ,  $I_{AS} = 5.0A$

③ 脉冲测试: 脉冲宽度 $\leq 300\mu s$ , 占空比 $\leq 2\%$

Pulse Test : Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$

## ● 特性曲线

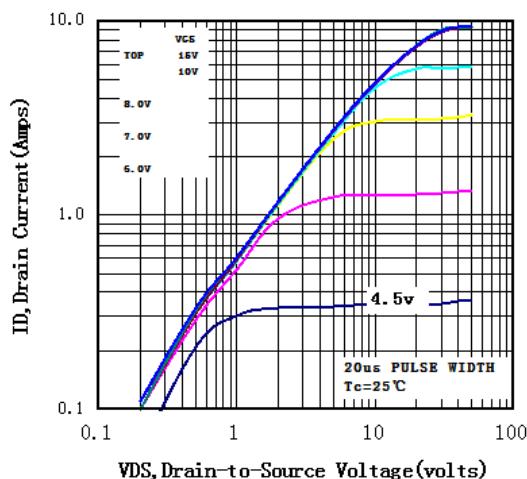


图1 输出特性曲线,  $T_c=25^\circ\text{C}$

Fig1 Typical Output Characteristics,  $T_c=25^\circ\text{C}$

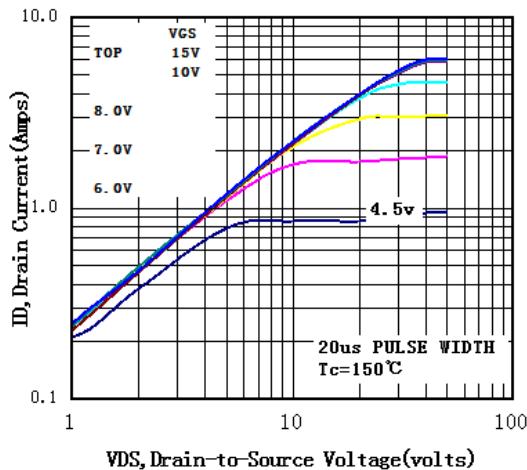


图2 输出特性曲线,  $T_c=150^\circ\text{C}$

Fig2 Typical Output Characteristics,  $T_c=150^\circ\text{C}$

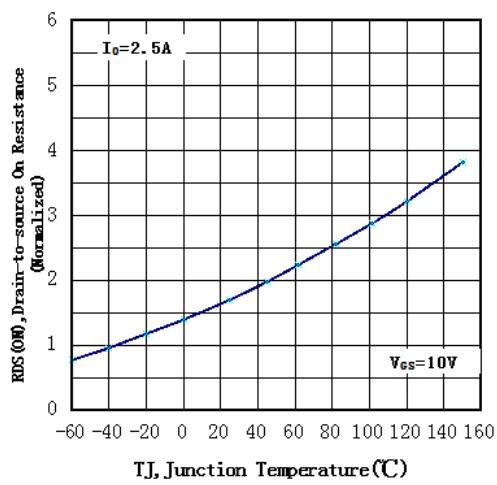


图3 归一化导通电阻与温度曲线  
Fig3 Normalized Resistance Vs.Temperature

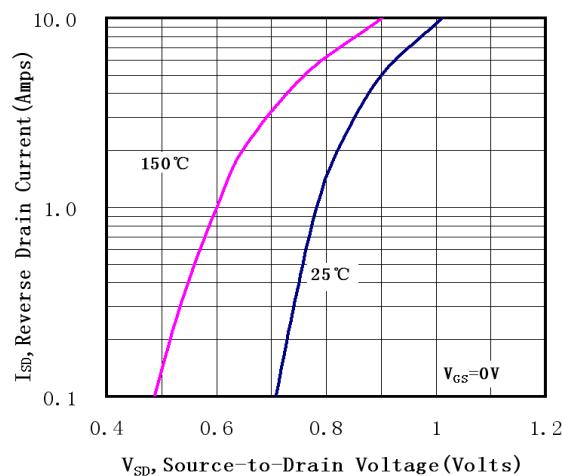


图4 二极管正向电压曲线  
Fig4 Typical Source-Drain Diode Forward Voltage

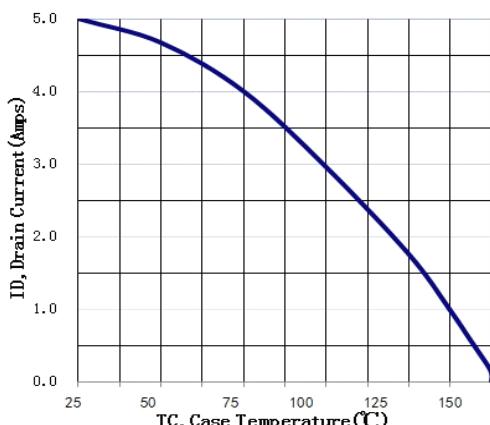


图5 最大漏极电流与壳温曲线  
Fig5 Maximum Drain Current Vs.Case Temperature

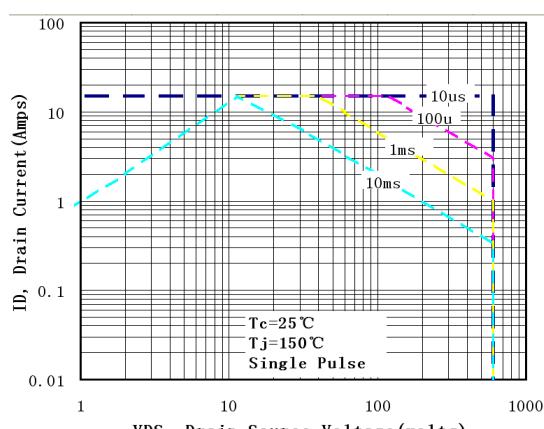


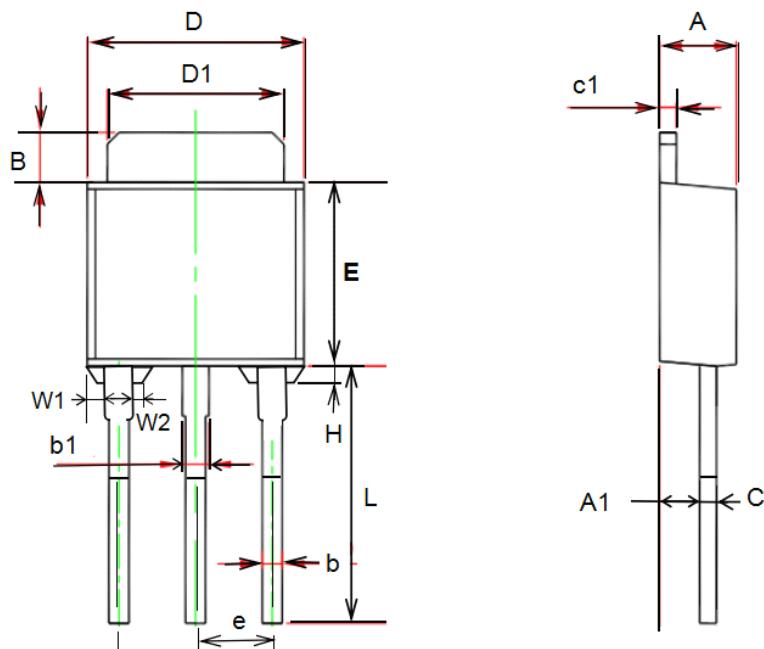
图6 最大安全工作区曲线  
Fig6 Maximum Safe Operating Area

## TO-251T 封装机械尺寸 TO-251T (IPAK) MECHANICAL DATA

单位:毫米/UNIT: mm

符号/SYMBOL	最小值/min	典型值/nom	最大值/max
A	2.10		2.50
A <sub>1</sub>	0.95		1.30
B	0.80		1.25
b	0.50		0.80
b <sub>1</sub>	0.70		0.80
c	0.45		0.70
c <sub>1</sub>	0.45		0.70
D	6.35		6.80
D <sub>1</sub>	5.10		5.50
E	5.30		6.30
e	2.25	2.30	2.35
L	7.00		9.20
H	0.35		0.45
W <sub>1</sub>	0.30		0.50
W <sub>2</sub>	0.20		0.40

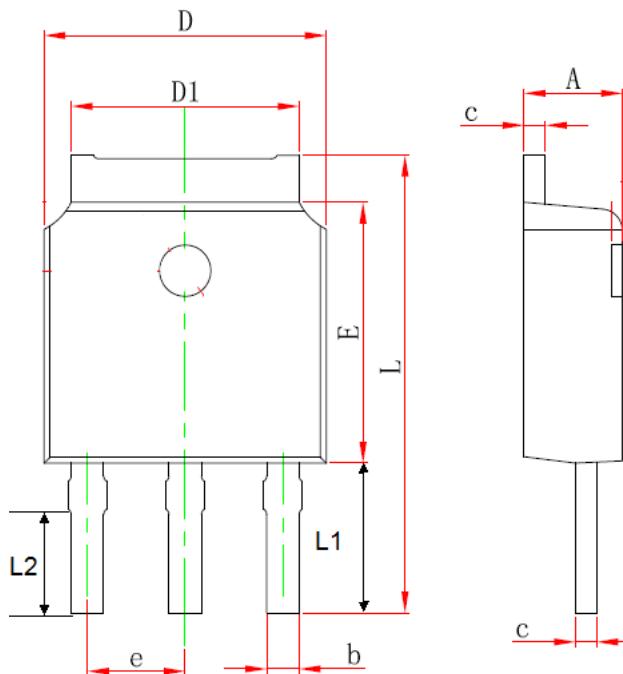
[S/L]



**TO-251S 封装机械尺寸  
TO-251S (IPAK) MECHANICAL DATA**

单位:毫米/UNIT: mm

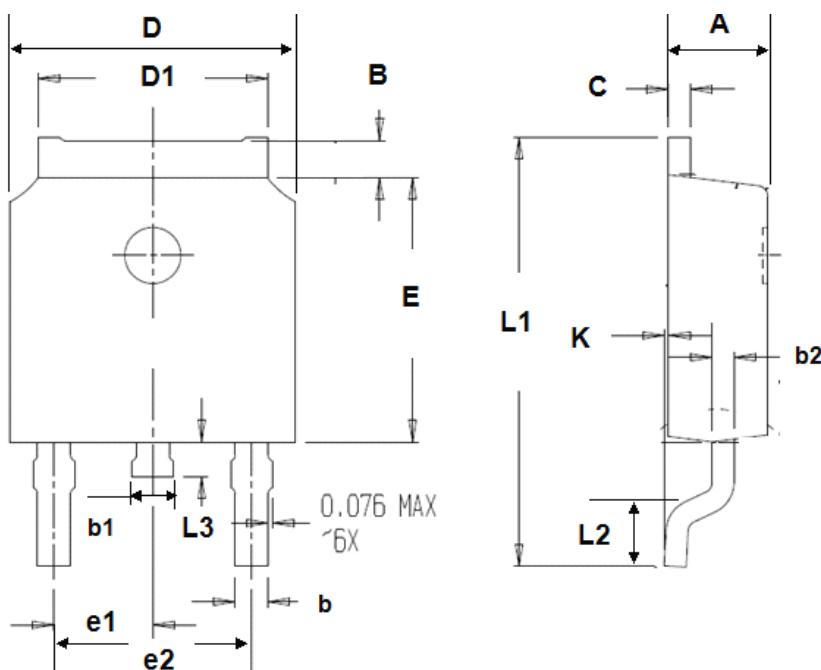
符号/SYMBOL	最小值/min	典型值/nom	最大值/max
A	2.20		2.40
b	0.60		0.85
C	0.45	0.50	0.60
D	6.50		6.70
D1	5.10		5.50
E	5.9		6.20
e	2.18	2.29	2.38
L	11.00		12.40
L1	4.8		5.3
L2	3.5		4.2



## TO-252 封装机械尺寸 TO-252 MECHANICAL DATA

单位:毫米/UNIT: mm

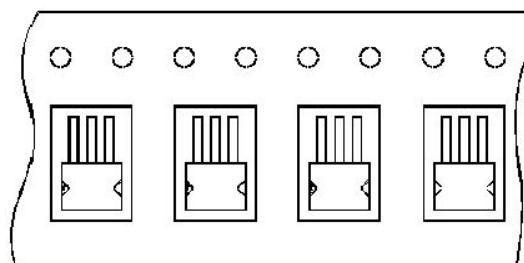
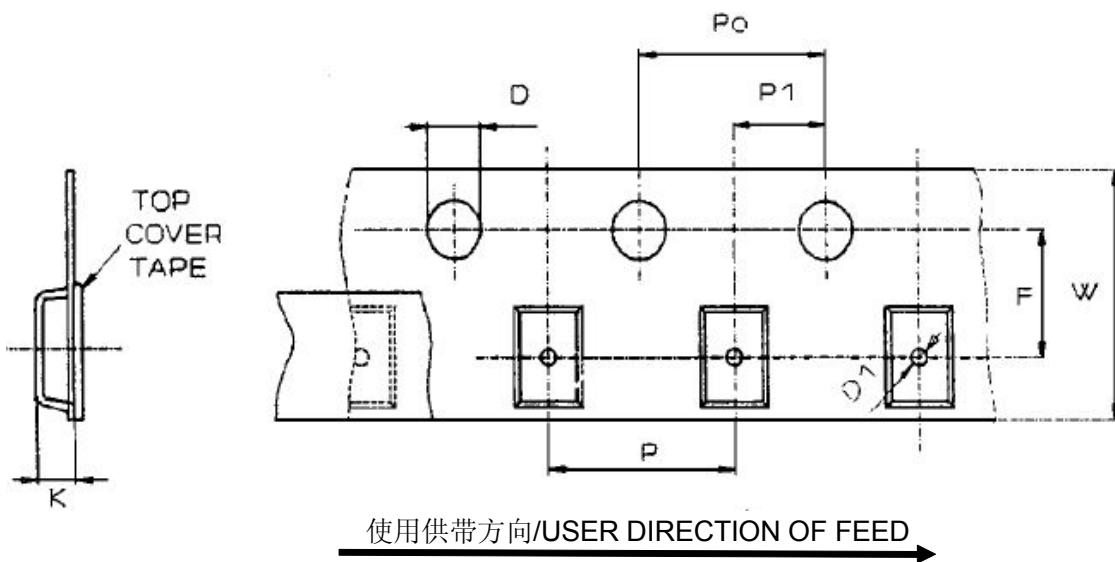
符号 <b>SYMBOL</b>	最小值 <b>min</b>	最大值 <b>max</b>	符号 <b>SYMBOL</b>	最小值 <b>min</b>	最大值 <b>max</b>
A	2.10	2.50	B	0.85	1.25
b	0.50	0.80	b1	0.50	0.90
b2	0.45	0.70	C	0.45	0.70
D	6.30	6.75	D1	5.10	5.50
E	5.30	6.30	e1	2.25	2.35
L1	9.20	10.60	e2	4.45	4.75
L2	0.90	1.75	L3	0.60	1.10
K	0.00	0.23			



**TO-252 编带规格尺寸  
TO-252 TAPE AND REEL DATA**

单位:毫米/UNIT: mm

符号 <b>SYMBOL</b>	最小值 <b>min</b>	最大值 <b>max</b>	符号 <b>SYMBOL</b>	最小值 <b>min</b>	最大值 <b>max</b>
W	16.0-0.3	16.0+0.3	F	7.5-0.1	7.5+0.1
P0	4.0-0.1	4.0+0.1	D	1.5-0.0	1.5+0.1
P	8.0-0.1	8.0+0.1	P1	2.0-0.1	2.0+0.1
K	2.65	2.80	D1	1.5-0.0	1.5+0.1



编带器件定位/UNIT ORIENTATION